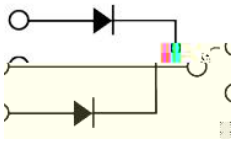
S1D040120D

TriQSiC™ 1200V Silicon Carbide Schottky Diode

Features





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Benefits

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Applications

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Table 1 Key performance and package parameters

Type	V_{RRM}	I_F	Q_C	Marking	Package

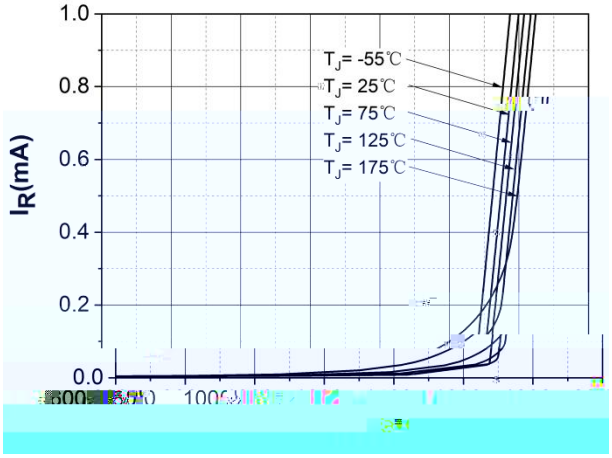
3 Electrical characteristics

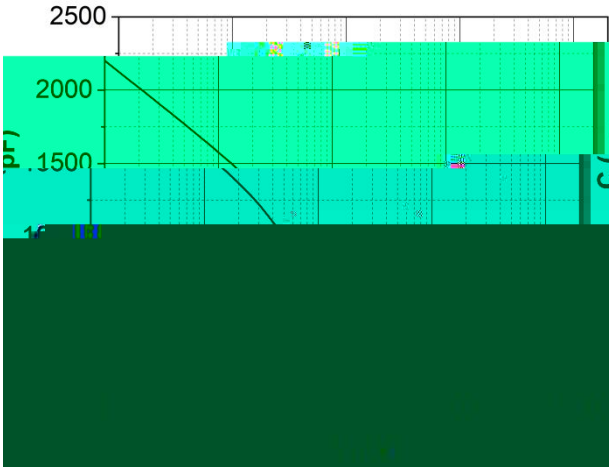
Table 4 Electrical characteristics

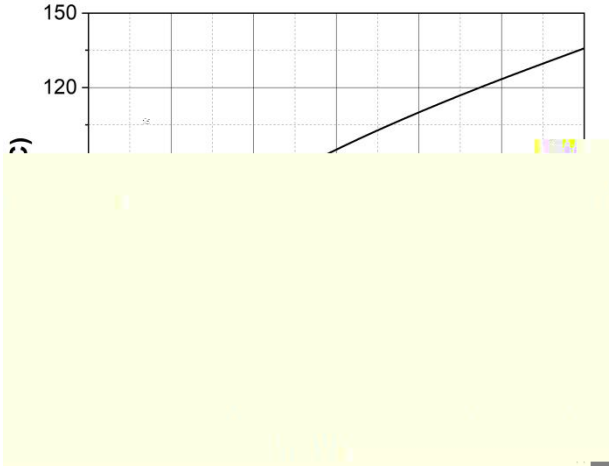
Symbol	Parameter	Typ.

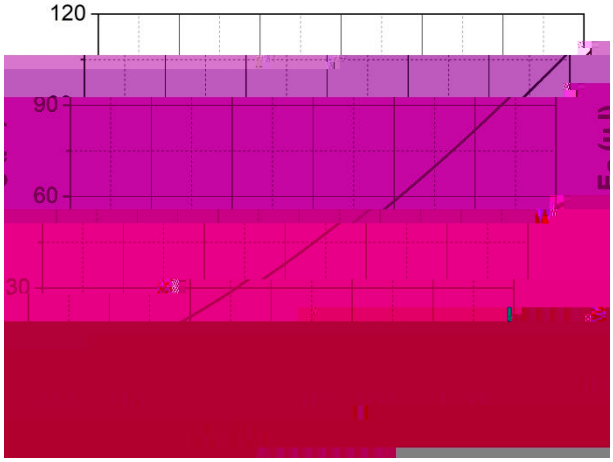
4 Electrical characteristic diagrams





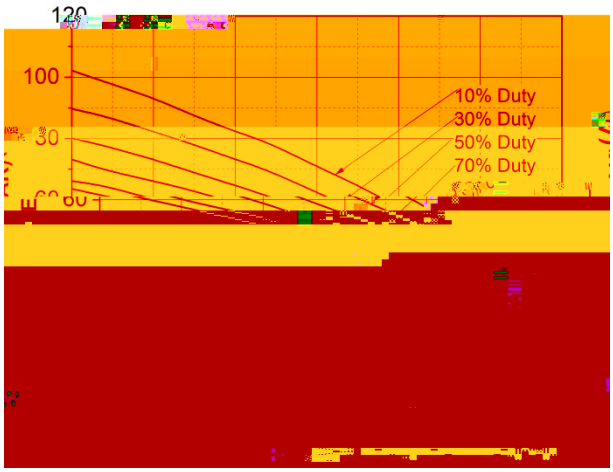


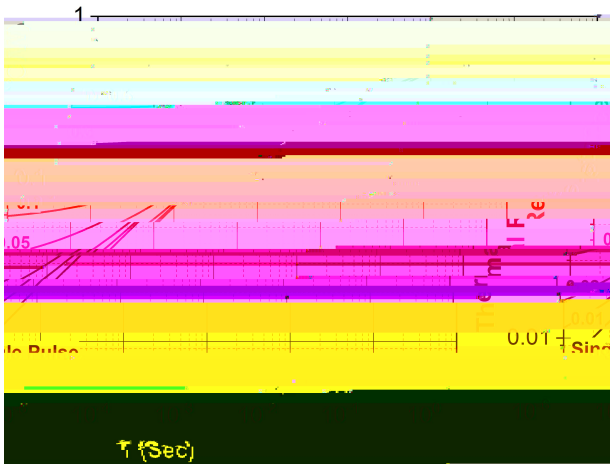






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1200V SiC Schottky Diode

Revision history

Document version	Date of release	Description of changes
V0ge00	2024-08-05	



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